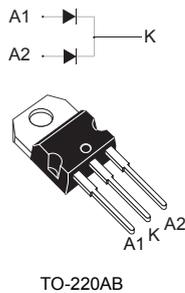


## 100 V, 40 A power Schottky rectifier



### Features

- Low forward voltage drop
- Good trade-off between leakage current and forward voltage drop
- High frequency operation
- Avalanche capability specified
- ECOPACK<sup>®</sup>2 compliant

### Applications

- Switching diode
- SMPS
- DC/DC converter
- LED lighting
- Adapter for notebook and game station

### Description

The **STPS40SM100C** is suited for high frequency switch mode power supply.

Packaged in TO-220AB, the **STPS40SM100C** is optimized for use in notebook and game station adaptors, providing in these applications a good efficiency at both low and high load.

#### Product status link

[STPS40SM100C](#)

#### Product summary

Symbol	Value
$I_{F(AV)}$	2 x 20 A
$V_{RRM}$	100 V
$T_j$ (max.)	150 °C
$V_F$ (typ.)	0.605 V

# 1 Characteristics

**Table 1. Absolute Ratings (limiting values, per diode, at 25 °C, unless otherwise specified)**

Symbol	Parameter		Value	Unit	
V <sub>RRM</sub>	Repetitive peak reverse voltage		100	V	
I <sub>F(RMS)</sub>	Forward rms current		60	A	
I <sub>F(AV)</sub>	Average forward current, $\delta = 0.5$ square wave	T <sub>C</sub> = 130 °C	Per diode	20	A
		T <sub>C</sub> = 125 °C	Per device	40	
I <sub>FSM</sub>	Surge non repetitive forward current	t <sub>p</sub> = 10 ms sinusoidal	350	A	
P <sub>ARM</sub>	Repetitive peak avalanche power	t <sub>p</sub> = 10 $\mu$ s, T <sub>j</sub> = 125 °C	1295	W	
T <sub>stg</sub>	Storage temperature range		-65 to +175	°C	
T <sub>j</sub>	Maximum operating junction temperature <sup>(1)</sup>		150	°C	

1.  $(dP_{tot}/dT_j) < (1/R_{th(j-a)})$  condition to avoid thermal runaway for a diode on its own heatsink.

**Table 2. Thermal resistance parameters**

Symbol	Parameter	Max. value	Unit
R <sub>th(j-c)</sub>	Junction to case	Per diode	1.3
		Total	0.7
R <sub>th(c)</sub>	Coupling	0.1	°C/W

When the diodes 1 and 2 are used simultaneously:

$$\Delta T_j(\text{diode1}) = P_{(\text{diode1})} \times R_{th(j-c)} (\text{per diode}) + P_{(\text{diode2})} \times R_{th(c)}$$

For more information, please refer to the following application note :

- AN5088 : Rectifiers thermal management, handling and mounting recommendations

**Table 3. Static electrical characteristics (per diode)**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit	
I <sub>R</sub> <sup>(1)</sup>	Reverse leakage current	T <sub>j</sub> = 25 °C	V <sub>R</sub> = 70 V	-	7		$\mu$ A
		T <sub>j</sub> = 125 °C		-	7		mA
		T <sub>j</sub> = 25 °C	V <sub>R</sub> = 100 V	-	13	45	$\mu$ A
		T <sub>j</sub> = 125 °C		-	13	45	mA
V <sub>F</sub> <sup>(2)</sup>	Forward voltage drop	T <sub>j</sub> = 25 °C	I <sub>F</sub> = 5 A	-	520		mV
		T <sub>j</sub> = 125 °C		-	435		
		T <sub>j</sub> = 25 °C	I <sub>F</sub> = 10 A	-	620	700	
		T <sub>j</sub> = 125 °C		-	520	580	
		T <sub>j</sub> = 25 °C	I <sub>F</sub> = 20 A	-	740	810	
		T <sub>j</sub> = 125 °C		-	605	665	

1. Pulse test: t<sub>p</sub> = 5 ms,  $\delta < 2\%$

2. Pulse test: t<sub>p</sub> = 380  $\mu$ s,  $\delta < 2\%$

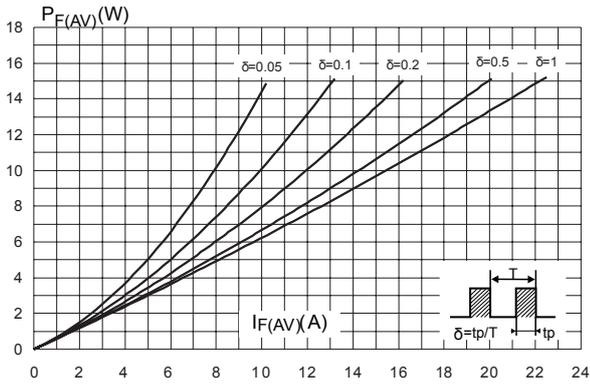
To evaluate the conduction losses, use the following equation:  $P = 0.580 \times I_{F(AV)} + 0.0043 \times I_F^2 (RMS)$

For more information, please refer to the following application notes related to the power losses :

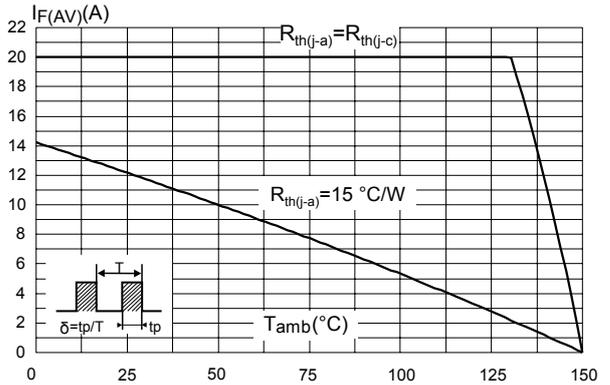
- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses on a power diode

## 1.1 Characteristics (curves)

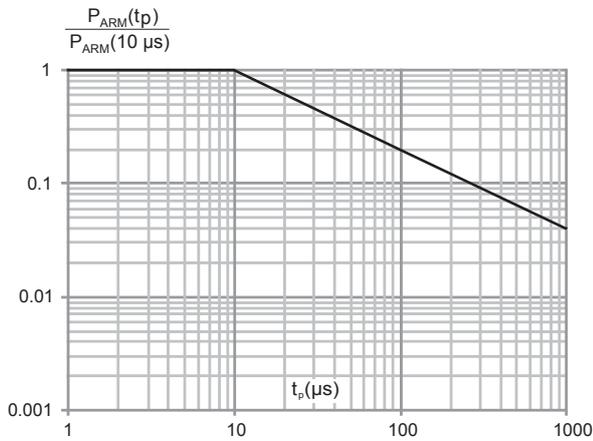
**Figure 1. Average forward power dissipation versus average forward current (per diode)**



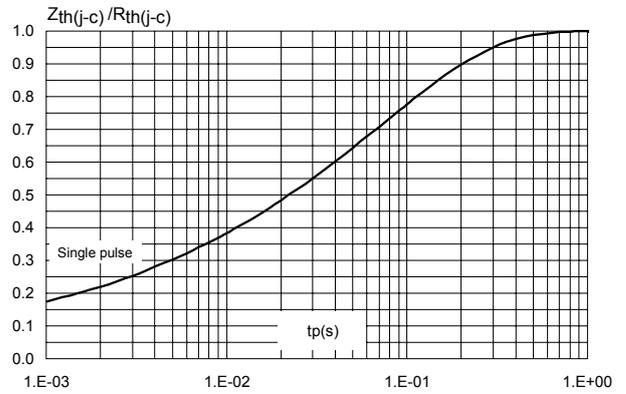
**Figure 2. Average forward current versus ambient temperature ( $\delta = 0.5$ , per diode)**



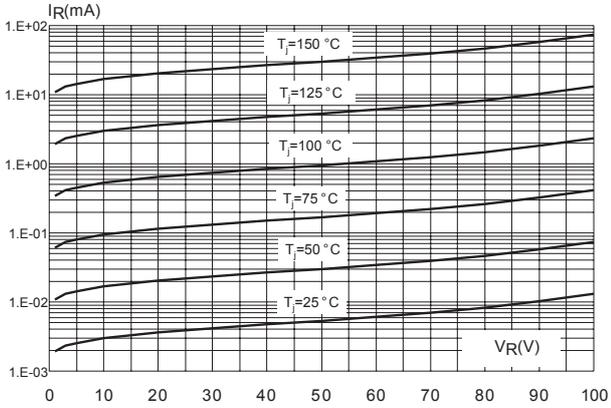
**Figure 3. Normalized avalanche power derating versus pulse duration ( $T_j = 125\text{ °C}$ )**



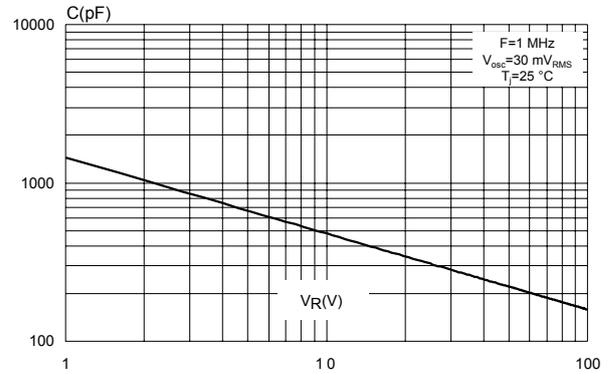
**Figure 4. Relative variation of thermal impedance junction to case versus pulse duration**



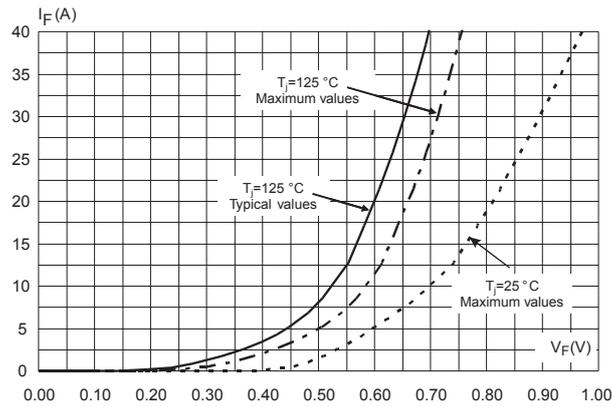
**Figure 5. Reverse leakage current versus reverse voltage applied (typical values, per diode)**



**Figure 6. Junction capacitance versus reverse voltage applied (typical values, per diode)**



**Figure 7. Forward voltage drop versus forward current (per diode)**





**Table 4. TO-220AB package mechanical data**

Ref.	Dimensions			
	Millimeters		Inches (for reference only)	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
b	0.61	0.88	0.240	0.035
b1	1.14	1.55	0.045	0.061
c	0.48	0.70	0.019	0.028
D	15.25	15.75	0.600	0.620
D1	1.27 typ.		0.050 typ.	
E	10.00	10.40	0.394	0.409
e	2.40	2.70	0.094	0.106
e1	4.95	5.15	0.195	0.203
F	1.23	1.32	0.048	0.052
H1	6.20	6.60	0.244	0.260
J1	2.40	2.72	0.094	0.107
L	13.00	14.00	0.512	0.551
L1	3.50	3.93	0.138	0.155
L20	16.40 typ.		0.646 typ.	
L30	28.90 typ.		1.138 typ.	
θP	3.75	3.85	0.148	0.152
Q	2.65	2.95	0.104	0.116

### 3 Ordering information

Table 5. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPS40SM100CT	PS40SM100CT	TO-220AB	1.95 g	50	Tube

## Revision history

**Table 6. Document revision history**

Date	Version	Changes
25-Mar-2009	1	First issue.
15-Apr-2010	2	Updated package graphics for TO-220AB on front page and in Table 5
27-Jun-2018	3	Updated Table 1. Absolute Ratings (limiting values, per diode, at 25 °C, unless otherwise specified) and Figure 3. Normalized avalanche power derating versus pulse duration ( $T_j = 125\text{ °C}$ ). Removed I <sup>2</sup> PAK and D <sup>2</sup> PAK package information.
22-Feb-2019	4	Updated Table 1.

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